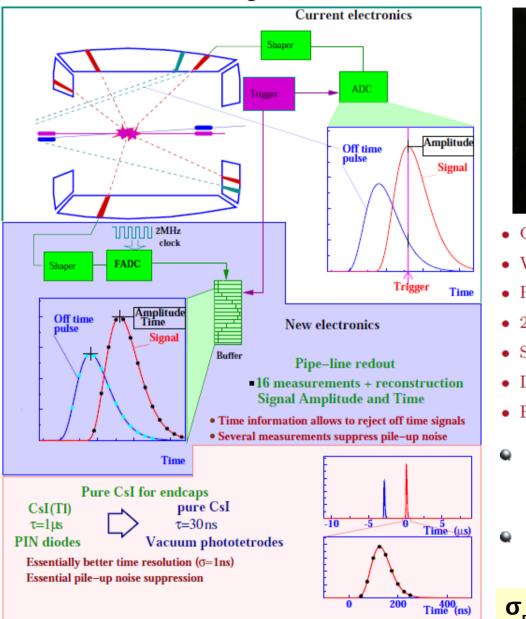


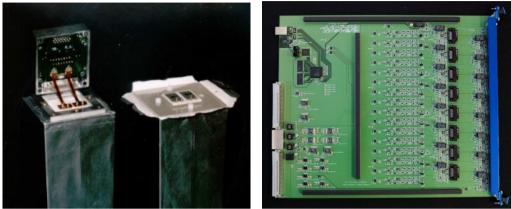
### Status of Csl(pure) + APD R&D Denis Epifanov (BINP) BINP July 3<sup>rd</sup>, 2025

# Outline:

- CsI(pure) for the Belle II ECL upgrade
- Csl(pure) + photopentode option I
- Csl(pure) + WLS(NOL-9) + 4APDs option II
- Works on **option II**, γ-beam test of the prototype, current status
- Summary

#### Belle II electromagnetic calorimeter (ECL) Belle II ECL is based on 8736 CsI(TI) crystals (40 tons) with the thickness of $16X_0$ (30 cm). It is located inside magnetic field of 1.5 T and covers the solid angle of 91% of $4\pi$ .





- Crystals 300x(50-80)x(50-80) mm
- Wrapping 200 $\mu m$  teflon+50  $\mu m$  Al mylar
- Readout 2 10x20 mm PIN diodes
- 2 charge sensitive preamplifiers
- Shaper CR-(RC)<sup>4</sup>,  $\tau = 1 \mu s$
- Lightoutput 5000 p.e./MeV
- Electronic noise  $1000e \approx 200 \text{ keV}$   $\stackrel{30 \text{ cm}}{-16.1 \text{ Xo}}$
- Electronics with pipe-line readout and waveform analysis (in the 16-ch Shaper-DSP board) has been developed. It is successfully being exploited now at Belle II.

Teflon+A1

CsI(T1)

To decrease **notable pileup noise** by a factor of √(1000 ns/30 ns)=5.8 in the endcap ECL (1152+960 ch), CsI(TI) crystals are planned to be changed to pure CsI crystals.

 $\sigma_{_{\rm F}}/{\rm E} \approx 1.8\%$  (E = 1GeV)  $\sigma_{_{\rm X}} = 6 \text{ mm}/\sqrt{\rm E(GeV)}$ 

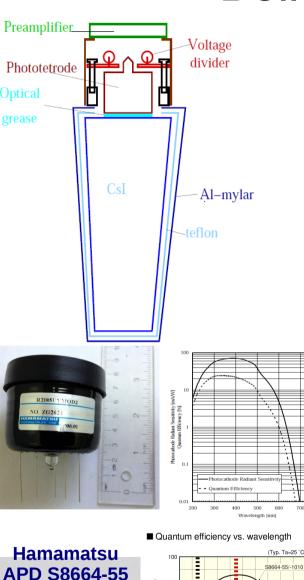
2 PIN diodes S2744-08

Acrylite

Al box

Preamp

# Belle II endcap ECL upgrade



**QUANTUM EFFICIENCY** 

1000

WAVELENGTH (nm

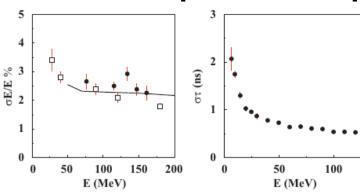


Fig. 5. Energy and time resolution obtained with the test beam (black points). The open squares present the earlier measurements with the Csl(Tl) crystals [7].



- To decrease pileup noise by a factor of 5.8 in the endcap ECL, it was suggested to change CsI(TI) to pure CsI crystals. R&D with CsI(pure) crystals and Hamamatsu photopentodes (PP) showed good results:
  - Low pileup noise, good energy and spatial resolution
  - Similar physical characteristics (as for CsI(TI)), better radiation hardness
  - There are several crystal producers, acceptable price
- However there are some difficulties: no redundancy, strong dependency on magnetic field, completely new mechanical support is needed. To solve these difficulties second R&D option was suggested: Csl(pure) + Si APD
- In the CsI(pure) + Si APD option we investigated Hamamatsu APD: S8664-1010 and S8664-55.
- With the actual size crystal and 1 APD (1 x 1 cm<sup>2</sup>) Hamamatsu S8664-1010 we obtained ENE ≈ 2 MeV, while the required ENE ≤ 0.4 MeV
- The main task was to reach admissible level of the electronic noise and the light output of the counter. The wavelength shifter with the nanostructured organosilicon luminophore (NOL-9) is used to improve the light output of the counter by a factor of ~4.

# Csl(pure)+WLS+4APD option (I)

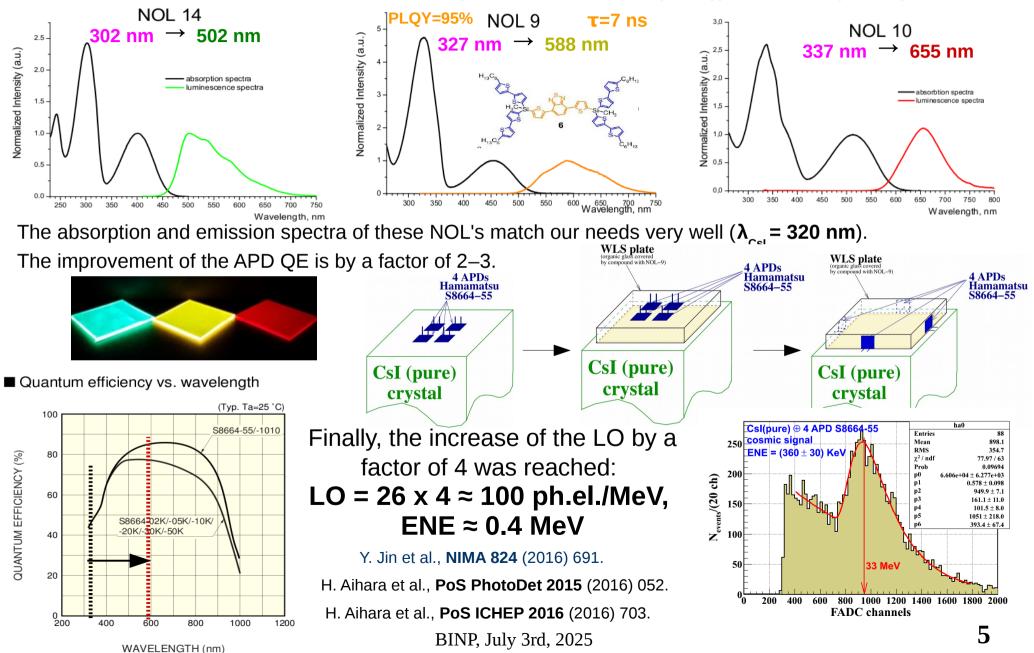
- The first tests showed that for the counter, based on the 6 x 6 x 30 cm<sup>3</sup> CsI(pure) crystal (AMCRYS) and 1 APD Hamamatsu S8664-1010 (1 cm<sup>2</sup>, C<sub>APD</sub> = 270 pF) coupled to the back facet of the crystal with optical grease (OKEN-6262A) has the light output <u>LO = 26</u> <u>ph.el./cm<sup>2</sup>/MeV</u> (for the shaping time of 30 ns), which corresponds to ENE ≈ 2 MeV. Such a small LO and large ENE substantially degrade the energy resolution of the calorimeter ( $\sigma_{E}/E$  (100 MeV) ≈ 8%). The acceptable parameters are: LO ≥ 150 ph.el./MeV, ENE < 0.4 MeV →  $\sigma_{E}/E$  (100 MeV) = 3.7% (3.4% from the fluctuations of the shower leakage)
- The reason of the small LO: small sensitive area of APD (1/36 of the area of the crystal facet), small quantum efficiency ((20 30)%) for the UV scintillation light (320 nm). The reason of large ENE = ENC/LO: small LO and large ENC (large capacitance of Hamamatsu S8664-1010, small shaping time  $\tau$  = 30 ns  $\rightarrow$  thermal noise  $\sim C_{APD}/(\sqrt{\tau} * g_{FET})$  dominates).
- The ways to improve LO and ENE:
  - − Increase the number of APDs (LO ~  $N_{APD}$ , ENE ~ 1/ $\sqrt{N_{APD}}$ ) → too expensive
  - Use smaller area APDs: 4 APDs S8664-55 (0.25 cm<sup>2</sup>,  $C_{APD} = 85 \text{ pF}$ ) (LO is the same, ENE is smaller by a factor of  $1/\sqrt{N_{APD}} = 0.5$ )

- Apply wavelength shifter (320 nm  $\rightarrow$  600 nm)
- Optimize the input circuit of the preamplifier (increase g<sub>FET</sub>)

We chose the configuration: Csl(pure) + WLS(nanostructured organosilicon luminophores) + 4APD (Hamamatsu S8664-55)

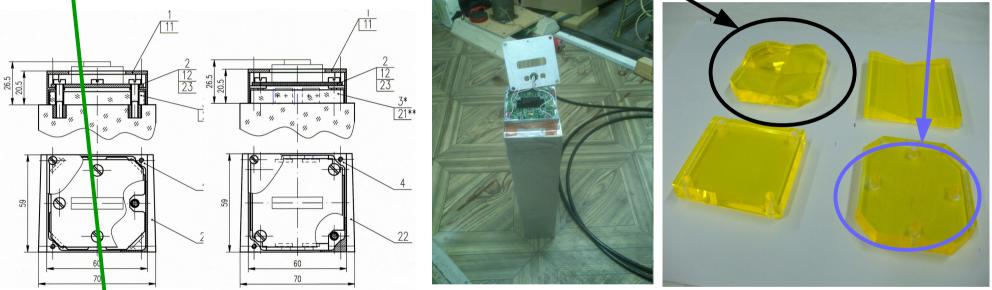
# Csl(pure) + WLS + 4APD option (II)

Based on the nanostructured organosilicon luminophores (NOL-9,10,14) from **LumInnoTech Co.**, the WLS plates were developed ((60 x 60 x 5) mm<sup>3</sup>).

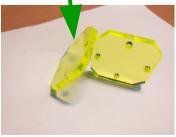


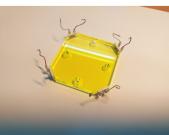
# Csl(pure) + WLS + 4APD option (III)

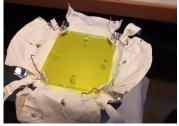
- Two types of mechanical construction of the counter were tested, the first variant was chosen.
- Electronic mounting of the counter was elaborated.
- WLS (NOL-9) plate of special shape was chosen (later, experimentally and with Geant4 MC we confirmed that ordinary flat plate is the best).
   The flat plates with the dissolved (in the bulk) NOL-9 luminophore will be used.
- Currently we use APDs, which have large dark current (Idark 60 nA) at the working point (pain = 50).

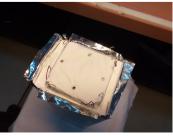


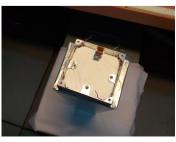
With cosmic particles the light output of the counter was measured to be LO = (62 ± 3) ph.el./MeV (before APD gain)











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#### Csl(pure) + WLS + 4APD option (IV) Crystals, WLS plates and APDs

- We constructed calorimeter prototype made of 16 counters, the parameters of available crystals (of 6 x 6 x 30 cm<sup>3</sup> size) were measured, mechanics was developed, produced and assembled.
- 64 Hamamatsu S8664-55 APDs were purchased from LHC CMS calorimeter group, baking procedure was held at CERN, the dark current was decreased by a factor of about 2.
- 16 WLS plates were purchased, APDs were coupled to the side edges of WLS plates with help of BC-600 optical epoxy resin. The WLS plates with APDs were tested in reference counter.



240

230

190

180

170

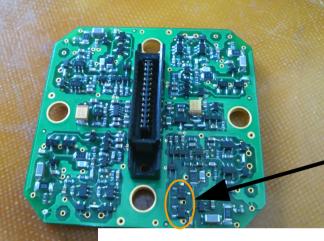
200

Amplitude of the cosmic peak position (ADC channels)

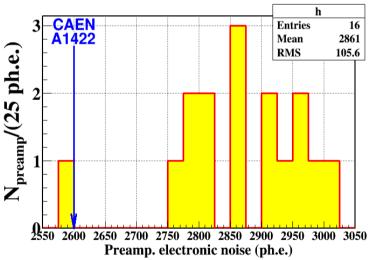
210

220

## Csl(pure) + WLS + 4APD option (V) 4-channel preamplifier and Shaper-ADC board



- **4-channel charge sensitive preamplifier** on 53 x 55 mm<sup>2</sup> PCB
- Each channel: sensitivity of 0.2 V/pC, 2 input FET 2SK932 (high transconductance), differential output, HV bias circuit, test pulse input

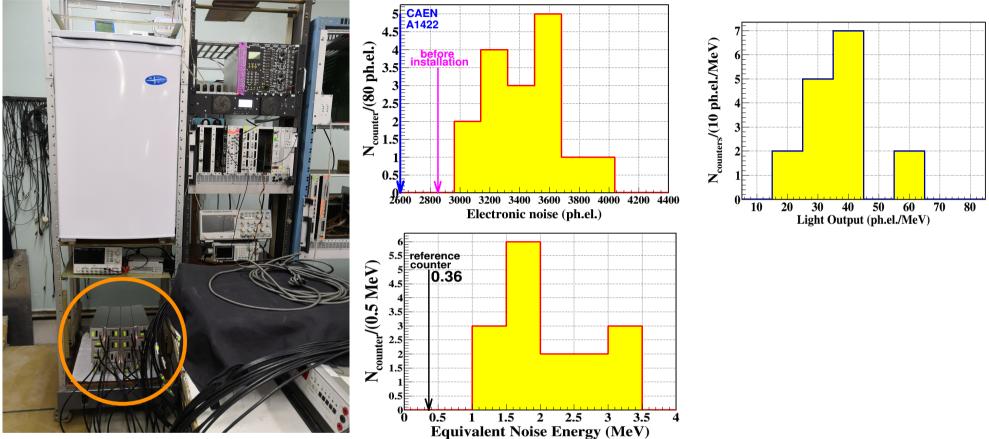




- 4-channel CAMAC Shaper-ADC board
- CR-(RC)<sup>4</sup> filter ( $\tau$  = 30 ns) + 40 MHz 12-bit pipelined ADC + 256-word circular buffer
- To comply with the new 4-ch preamp additional differential receiver and summator (DRS) boards have been produced and mounted in the Shaper-ADC boards BINP, July 3rd, 2025

# Prototype

 Assembly of 16 counters of the prototype was done, main characteristics were measured. Cosmic and pulse generator runs with the prototype are used for the calibration.



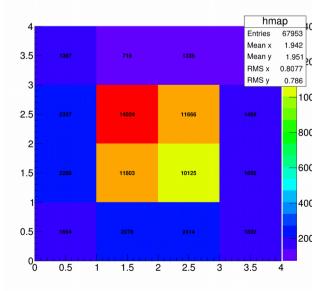
- The best counter has the light output of only LO = 62 ph.el./MeV, it is related to the LO without WLS of only LO = 15 ph.el./MeV, which is 1.7 times smaller than the LO without WLS of U-Tokyo counter (26 ph.el./MeV).
- Also, the electronic noise of the best counter, ENC = 4000 el., is 1.5 times larger than that of U-Tokyo counter (ENC = 2600 el.) because of the large APD dark current (Id = 260 nA), and, hence large shot noise (becoming similar to the thermal noise).
- These two factors explain why the ENE of the best counter is now about ENE = 1 MeV (to be compared with ENE of U-Tokyo counter ENE = 0.4 MeV).

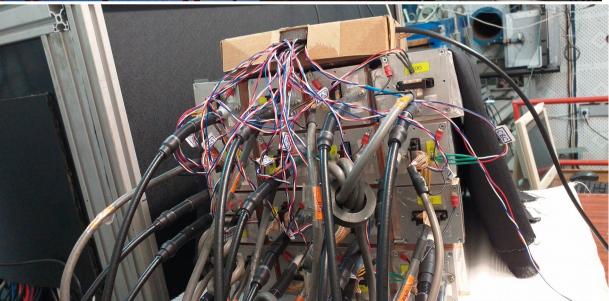


## Beam test of the prototype (I)

#### Was held in June 2023 at the ROKK-1M test beam facility in BINP



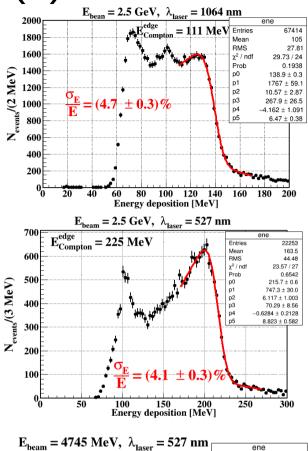




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#### Beam test of the prototype (II)

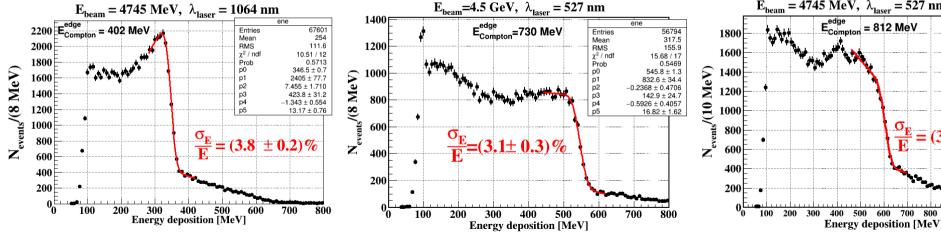
VEPP-4M e- beam energy, MeV	Laser mode, nm	Energy of the Compton edge, MeV	# events
1900	1064	<mark>64</mark>	880k
2500	1064	111	1060k
2500	527	<mark>225</mark>	1550k
4500	1064	<mark>361</mark>	630k
4745	1064	<mark>402</mark>	800k
3500	527	<mark>441</mark>	900k
4500	527	<mark>730</mark>	1350k
4745	527	<mark>812</mark>	800k
		Total:	8M



= 812 MeV

Energy deposition [MeV]

E<sup>edge</sup> Compton



900 1000 1100 1200

92859

387.2

24.1 / 18

0.1516

 $605.7 \pm 2.1$ 

1226 ± 50.4

-2.826 ± 0.462

-0.7315 ± 0.5916

 $424.3 \pm 42.9$ 

 $20.8 \pm 2.8$ 

206

Entries

Mean

RMS

Prob

p0

p1

p2

. рЗ

p4

. p5

 $= (3.4 \pm 0.5)\%$ 

 $\chi^2$  / nd

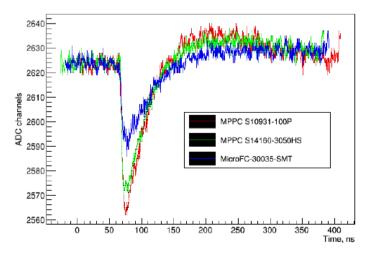
#### Beam test of the prototype (III) **Prototype energy resolution** 10Preliminary /There is remaining ~3% contribution to the energy resolution due to the *rough* - EXP cosmic calibration of the counters in the Total prototype (will be improved). $\sigma_{\rm E}/{\rm E}$ [%] It is seen that at the energies $<\sim 0.2$ GeV the *contribution of the electronic noise* of the counters to the prototype energy resolution *dominates*. **Only leakage** Works to decrease electronic noises are going on. 0.4 0.5 0.6 0.7 0.8 0.9 0.1 0.3 1 0.2 **Energy** [GeV] $\frac{\sigma_{E}}{E} = \frac{1.9\%}{\sqrt[4]{E[GeV]}} \oplus \frac{Stat}{\sqrt{E[GeV]}} \oplus \frac{Elec}{E[GeV]}$ $F = 1.69 \pm 0.04$ $Stat = 100\% \cdot \sqrt{\frac{F}{S[ph.e/MeV] \cdot N_{APD} \cdot 1000}} = 0.63\%$ S·N<sub>APD</sub> = 42 ph.el./MeV **ENE = 1.7 MeV** $Elec = 100\% \cdot \frac{ENE[MeV] \cdot \sqrt{N_{crys}}}{1000} = 0.54\%$ $N_{crys} = 10 - number of$ crystals in the 1 GeV cluster

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12

#### Works with SiPM

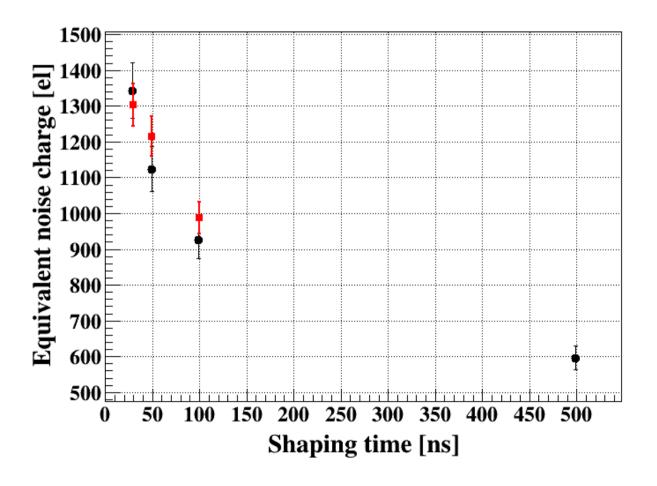
- For the precise time measurement it is suggested to install several SiPMs in the counter in addition to the APD-based spectrometric channel.
- In the perspective this scheme will allow one to measure the incident angle of γ-quantum as well as its production point in the detector.
- One counter of the prototype was equipped by two SiPMs Hamamatsu MPPC S14160-3050HS (3 x 3 мм<sup>2</sup>). The signals from SiPMs were digitized by CAEN V1742B. The obtained light output is 10 ph.e./MeV/cm<sup>2</sup>, the time resolution was measured to be 23 ns/MeV + 70 ps.
- Plan to install 16 SiPMs (Broadcom AFBR-S4N66C013 6x6 mm<sup>2</sup>) into 16 counters of the prototype and measure time resolution.



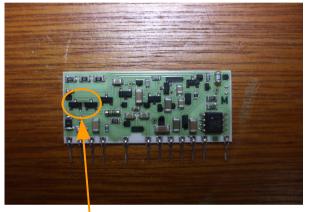


### Study of the BINP preamplifier

- Noise characteristics of BINP preamplifier were measured and compared with • those of CAEN A1422B045F3.
- Both preamplifiers have the same equivalent noise charge (ENC). At the • shaping time of 30 ns, the preamplifiers have the minimal possible ENC  $\approx$  1300 el. (determined by the parameters of the best FET (BF862, 2SK932-23) installed in the preamp. input circuit).



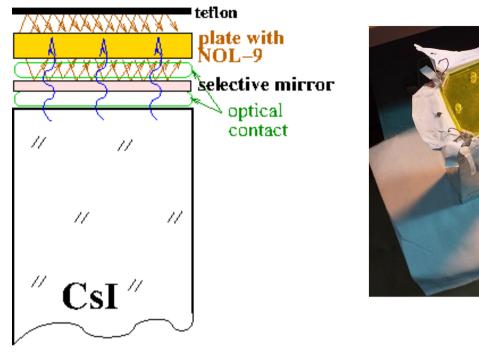
CAEN A1422B045F3

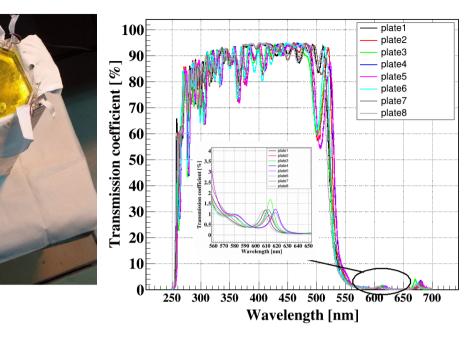


2 BF862 FETs



#### Work with selective mirrors





- Selective mirror increases the light collection efficiency due to the optical contact (grease/resin), which allows one to direct more (x 2.3) light to the plate with NOL-9.
- A challenge for the mirror is to achieve high transmission coefficient for the UV light (~100%) of pure CsI, and high reflection coefficient (>99.7%) for the emitted in the plate visible light.
- Currently we are developing the structure of mirror coating.

# Summary & Plans

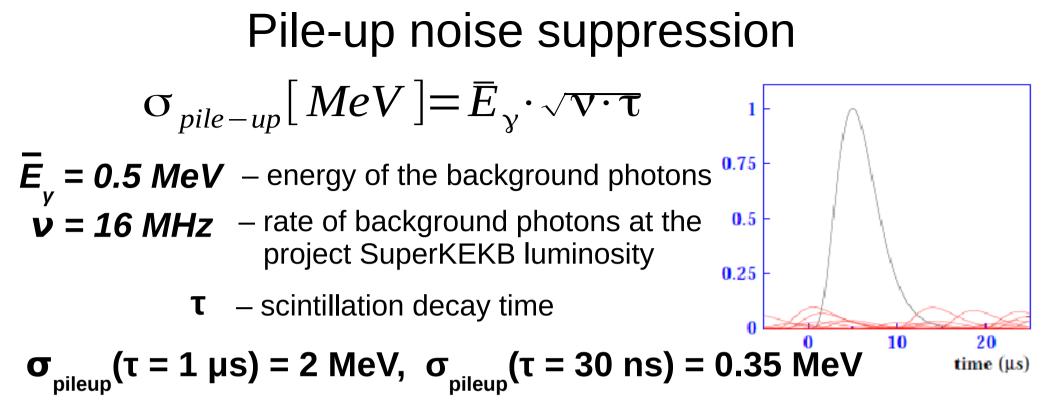
- Csl(pure) is an appropriate material for the fast calorimeter.
- Beam tests of the 20-counter prototype based on CsI(pure) crystals and vacuum photopentodes showed good energy and spatial resolutions, as well as essential suppression of the pileup noise.
- The CsI(pure)+WLS+4APDs option is also quite promising. The 16-counter calorimeter prototype has been constructed. Due to the small light yield of the utilized CsI(pure) crystals and big electronic noises (ENC) the ENE is still quite high, which results in the low energy resolution of the prototype at small energies  $E_v$ <~0.3 GeV.
- Test beam study of the prototype at the ROKK-1M facility in BINP was performed in June 2023. The preliminary result on the energy resolution of the prototype agrees with the expectations.
- The developed preamplifier has optimal ENC = 1300 el ( $@\tau$ =30 ns).
- Further improvement of the light output of the counter is possible with an <u>additional selective mirror</u>, the work is going on.
- SiPM can be used for both time measurement as well as to provide fast trigger signal.

# Backups

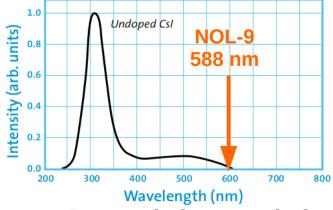
# Choice of the crystal

crystal	ρ,	$\mathbf{X}_{0},$	$\lambda_{em},$	n	$N_{ph}/MeV$	au,
	$g/cm^3$	cm	nm			$\mathbf{ns}$
CsI(Tl)	4.51	1.86	550	1.8	52000	1000
$\mathbf{CsI}$	4.51	1.86	305/400	2	5000	30/1000
$BaF_2$	4.89	2.03	220/310	1.56	2500/6500	0.6/620
${f CeF_3}$	6.16	1.65	310	1.62	600	3
$PbWO_4$	8.28	0.89	430	2.2	25	10
${f LuAlO_3(Ce)}$	8.34	1.08	365	1.94	20500	18
${ m Lu_3Al_5O_{12}(Ce)}$	7.13	1.37	510	1.8	5600	60
${ m Lu}_2{ m SiO}_5({ m Ce})$	7.41	1.2	420	1.82	26000	12/40

- CsI(TI) has the largest LY, small scintillation decay time and modest price (~3\$/cm<sup>3</sup>). It is used in the electromagnetic calorimeters of modern particle detectors: Belle, Belle II, BaBar, BES-III, CMD-3.
- Lu<sub>2</sub>SiO<sub>5</sub> (LSO), LuAlO<sub>3</sub>, LYSO are also very good (and much faster than CsI(TI)), however they are essentially more expensive ((15 – 30)\$/cm<sup>3</sup>), COMET (2000 LYSO crystals).
- Pure CsI has still notable LY, fast decay time component of 30 ns and acceptable price (~6\$/cm<sup>3</sup>). The are several crystal-growing companies which are able to produce needed number of large size crystals (~40 tons): AMCRYS(Ukraine), Saint Gobain (France), HPK (Japan-China), SICCAS (China)



Long scintillation light decay time component of CsI(pure) is notable (up to 50%) with  $\tau \ge 1 \mu s$ . It has larger wavelength (in the visible range: (400 – 600) nm). So, there is additional pile-up noise due to these long tails of the previous pulses (from both, signal and background).



# **Solution (KTeV experiment):** *additional optical filter to cut this long decay time component*

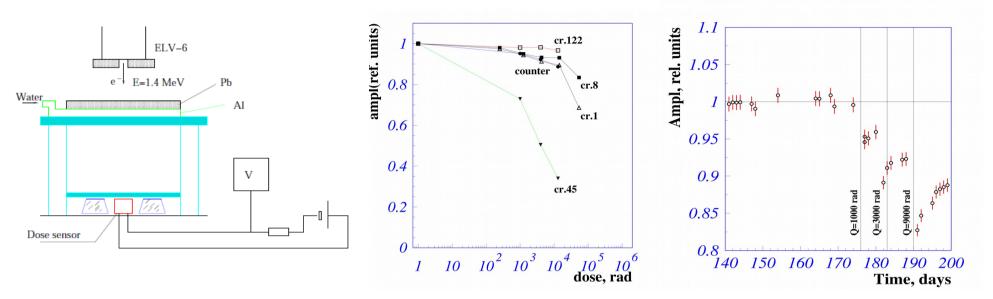
We can add filter between CsI(pure) crystal and WLS plate. In case of NOL-9, half of the re-emitted light will be rejected by the filter. We can change WLS and use, for example, NOL-10. Or use narrower filter ((400 - 540) nm)

Spectral characteristics of the long decay time component of Csl(pure) should be studied to choose optimal scheme

BINP, July 3rd, 2025

# Study of radiation hardness of Csl(pure) crystals

I. Bedny et al., NIMA598 (2009) 273. A. Boyarintsev et al., JINST11 (2016) P03013.



- We studied the radiation hardness of 4 CsI(pure) crystals and 1 counter (CsI(pure) + photopentode), they were irradiated by bremsstrahlung  $\gamma$ 's with  $E_{\gamma} < 1.4$  MeV
- The dose rate was controlled by ELV-6 current and measured by a special dosimeter made of CsI(TI) crystal and PIN PD
- For the dose of 15 krad the degradation of the LO of 3 crystals and counter was less than 15%, **but the** degradation of the LO of one counter turned out to be about 60%, it was recovered to about 80% within one year. No change if the Fast/Total-ratio was detected within the accuracy of 3%.
- Csl(pure) crystals were also irradiated by neutrons (up to 10<sup>12</sup> 1/cm<sup>2</sup>), we didn't detect any LO degradation within the accuracy of 5%
- The procedure to reject Csl(pure) crystals with poor radiation hardness should be developed